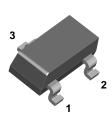
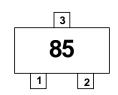


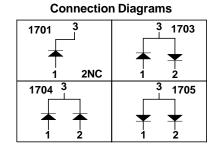
MMBD1701/A / 1703/A / 1704/A / 1705/A



SOT-23



MARKING MMBD1701 85 MMBD1701A 85A MMBD1703 87 MMBD1703A 87A MMBD1704 88 MMBD1704A 88A MMBD1705 89 MMBD1705A 89A



Small Signal Diodes

Absolute Maximum Ratings*

T_a = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|--------------------|--|-------------|-------|
| V_{RRM} | Maximum Repetitive Reverse Voltage | 30 | V |
| I _{F(AV)} | Average Rectified Forward Current | 50 | mA |
| I _{FSM} | Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second | 250 | mA |
| T _{stg} | Storage Temperature Range | -55 to +150 | °C |
| T _J | Operating Junction Temperature | 150 | °C |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

| Symbol | Parameter | Value | Units |
|-----------------|---|-------|-------|
| P _D | Power Dissipation | 350 | mW |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357 | °C/W |

Electrical Characteristics T_A = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
|-----------------|-------------------------------------|---|---|--|---------------------------|
| V_R | Breakdown Voltage | I _R = 5.0 μA | 30 | | V |
| V _F | Forward Voltage | $\begin{array}{l} I_F = 10 \; \mu A \\ I_F = 100 \; \mu A \\ I_F = 1.0 \; mA \\ I_F = 10 \; mA \\ I_F = 20 \; mA \\ I_F = 50 \; mA \end{array}$ | 420 520 640 760 810 0.89 | 500 610 740 880 950 1.1 | mV mV mV mV V |
| I _R | Reverse Current | V _R = 20 V | | 50 | nA |
| Ст | Total Capacitance | V _R = 0, f = 1.0 MHz | | 1.0 | pF |
| t _{rr} | Reverse Recovery Time MMBD1701-1705 | $I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_1 = 100 \Omega$ | | 0.7 | ns |
| | MMBD1701A-1705A | $I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_L = 100 \Omega$ | | 1.0 | ns |

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Small Signal Diode

(continued)

Typical Characteristics

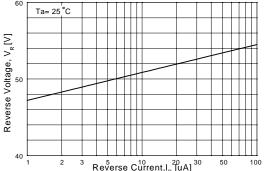


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to 100 uA

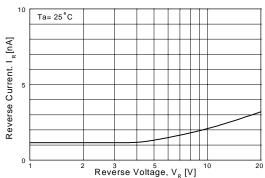


Figure 2. Reverse Current vs Reverse Voltage IR - 1 to 22V

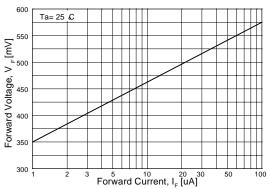


Figure 3. Forward Voltage vs Forward Current VF - 1.0 to 100 uA

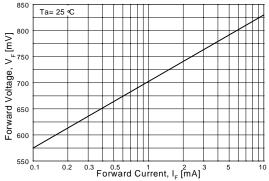


Figure 4. Forward Voltage vs Forward Current VF - 0.1 to 10 mA

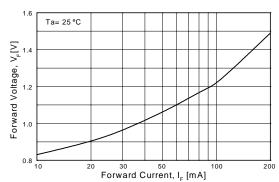


Figure 5. Forward Voltage vs Forward Current VF - 10 - 200 mA

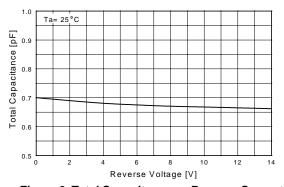


Figure 6. Total Capacitance vs Reverse Current

Small Signal Diode

(continued)

Typical Characteristics (continued)

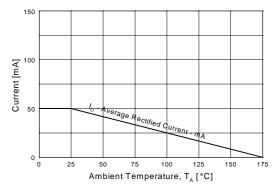


Figure 7. Average Rectified Current (I_o) versus Ambient Temperature (T_A)

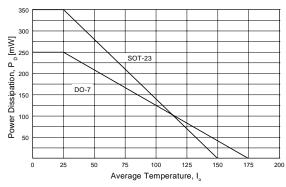


Figure 8. Power Derating Curve

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|--------------------------|---------------------------|---|
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